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CMOS Power Metrics Formulas

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List of 17 CMOS Power Metrics Formulas

CMOS Power Metrics ↗

1) Activity Factor ↗

$$fx \quad \alpha = \frac{P_s}{C \cdot V_{bc}^2 \cdot f}$$

[Open Calculator ↗](#)

$$ex \quad 1.625491 = \frac{0.13mW}{4.9\mu F \cdot (2.02V)^2 \cdot 4Hz}$$

2) Capacitive Load Power Consumption ↗

$$fx \quad P_L = C_L \cdot V_{cc}^2 \cdot f_o \cdot S_{wo}$$

[Open Calculator ↗](#)

$$ex \quad 2.944254mW = 5.01\mu F \cdot (1.55V)^2 \cdot 61Hz \cdot 4.01$$

3) Contention Current in Ratioed Circuits ↗

$$fx \quad i_{con} = \left(\frac{P_{st}}{V_{bc}} \right) - (i_{st} + i_g + i_j)$$

[Open Calculator ↗](#)

$$ex \quad 25.75149mA = \left(\frac{67.37mW}{2.02V} \right) - (1.6mA + 4.5mA + 1.5mA)$$



4) Dynamic Power in CMOS 

$$fx \quad P_{dyn} = P_{sc} + P_s$$

Open Calculator 

$$ex \quad 46.13mW = 46mW + 0.13mW$$

5) Gate Leakage through Gate Dielectric 

$$fx \quad i_g = \left(\frac{P_{st}}{V_{bc}} \right) - (i_{st} + i_{con} + i_j)$$

Open Calculator 

$$ex \quad 4.501485mA = \left(\frac{67.37mW}{2.02V} \right) - (1.6mA + 25.75mA + 1.5mA)$$

6) Gates on Critical Path 

$$fx \quad N_g = D \cdot \frac{i_{off} \cdot (10^V - \{bc\})}{C_g \cdot [BoltZ] \cdot V_{bc}}$$

Open Calculator 

$$ex \quad 0.000957 = 1.3E^{-25} \cdot \frac{0.01mA \cdot (10^{2.02V})}{5.1mF \cdot [BoltZ] \cdot 2.02V}$$

7) Leakage Energy in CMOS 

$$fx \quad E_{leak} = E_t - E_s$$

Open Calculator 

$$ex \quad 7pJ = 42pJ - 35pJ$$



8) Output Switching at Load Power Consumption ↗

$$fx \quad S_{wo} = \frac{P_L}{C_L \cdot V_{cc}^2 \cdot f_o}$$

[Open Calculator ↗](#)

$$ex \quad 4.004206 = \frac{2.94mW}{5.01\mu F \cdot (1.55V)^2 \cdot 61Hz}$$

9) Power Supply Rejection Ratio ↗

$$fx \quad P_{sr} = 20 \cdot \log 10 \left(\frac{V_{in}}{V_{out}} \right)$$

[Open Calculator ↗](#)

$$ex \quad 2.963504dB = 20 \cdot \log 10 \left(\frac{7.23V}{5.14V} \right)$$

10) Short-Circuit Power in CMOS ↗

$$fx \quad P_{sc} = P_{dyn} - P_s$$

[Open Calculator ↗](#)

$$ex \quad 46mW = 46.13mW - 0.13mW$$

11) Static Power in CMOS ↗

$$fx \quad P_{st} = P_t - P_{dyn}$$

[Open Calculator ↗](#)

$$ex \quad 67.37mW = 113.5mW - 46.13mW$$



12) Subthreshold Leakage through OFF Transistors ↗

fx $i_{st} = \left(\frac{P_{st}}{V_{bc}} \right) - (i_g + i_{con} + i_j)$

[Open Calculator ↗](#)

ex $1.601485\text{mA} = \left(\frac{67.37\text{mW}}{2.02\text{V}} \right) - (4.5\text{mA} + 25.75\text{mA} + 1.5\text{mA})$

13) Switching Energy in CMOS ↗

fx $E_s = E_t - E_{leak}$

[Open Calculator ↗](#)

ex $35\text{pJ} = 42\text{pJ} - 7\text{pJ}$

14) Switching Power ↗

fx $P_s = \alpha \cdot (C \cdot V_{bc}^2 \cdot f)$

[Open Calculator ↗](#)

ex $0.13196\text{mW} = 1.65 \cdot (4.9\mu\text{F} \cdot (2.02\text{V})^2 \cdot 4\text{Hz})$

15) Switching Power in CMOS ↗

fx $P_s = (V_{dd}^2) \cdot f \cdot C$

[Open Calculator ↗](#)

ex $0.130465\text{mW} = ((2.58\text{V})^2) \cdot 4\text{Hz} \cdot 4.9\mu\text{F}$

16) Total Energy in CMOS ↗

fx $E_t = E_s + E_{leak}$

[Open Calculator ↗](#)

ex $42\text{pJ} = 35\text{pJ} + 7\text{pJ}$



17) Total Power in CMOS 

fx
$$P_t = P_{st} + P_{dyn}$$

Open Calculator 

ex
$$113.5\text{mW} = 67.37\text{mW} + 46.13\text{mW}$$



Variables Used

- C Capacitance (*Microfarad*)
- C_g Capacitance of Gate to Channel (*Millifarad*)
- C_L External Load Capacitance (*Microfarad*)
- D Duty Cycle
- E_{leak} Leakage Energy in CMOS (*Picojoule*)
- E_s Switching Energy in CMOS (*Picojoule*)
- E_t Total Energy in CMOS (*Picojoule*)
- f Frequency (*Hertz*)
- f_o Output Signal Frequency (*Hertz*)
- i_{con} Contention Current (*Milliampere*)
- i_g Gate Current (*Milliampere*)
- i_j Junction Current (*Milliampere*)
- i_{off} Off Current (*Milliampere*)
- i_{st} Subthreshold Current (*Milliampere*)
- N_g Gates on Critical Path
- P_{dyn} Dynamic Power (*Milliwatt*)
- P_L Capacitive Load Power Consumption (*Milliwatt*)
- P_s Switching Power (*Milliwatt*)
- P_{sc} Short-Circuit Power (*Milliwatt*)
- P_{sr} Power Supply Rejection Ratio (*Decibel*)
- P_{st} CMOS Static Power (*Milliwatt*)



- P_t Total Power (Milliwatt)
- S_{wo} Output Switching
- V_{bc} Base Collector Voltage (Volt)
- V_{cc} Supply Voltage (Volt)
- V_{dd} Positive Voltage (Volt)
- V_{in} Input Voltage Ripple (Volt)
- V_{out} Output Voltage Ripple (Volt)
- α Activity Factor



Constants, Functions, Measurements used

- **Constant:** **[BoltZ]**, 1.38064852E-23 Joule/Kelvin
Boltzmann constant
- **Function:** **log10**, $\log_{10}(\text{Number})$
Common logarithm function (base 10)
- **Measurement:** **Electric Current** in Milliampere (mA)
Electric Current Unit Conversion ↗
- **Measurement:** **Energy** in Picojoule (pJ)
Energy Unit Conversion ↗
- **Measurement:** **Power** in Milliwatt (mW)
Power Unit Conversion ↗
- **Measurement:** **Noise** in Decibel (dB)
Noise Unit Conversion ↗
- **Measurement:** **Frequency** in Hertz (Hz)
Frequency Unit Conversion ↗
- **Measurement:** **Capacitance** in Microfarad (μF), Millifarad (mF)
Capacitance Unit Conversion ↗
- **Measurement:** **Electric Potential** in Volt (V)
Electric Potential Unit Conversion ↗



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